

# 2.6 Watt Mono Filter-Free Class-D Audio Power Amplifier

# **Features**

 $\Box$  Efficiency With an 8- $\Omega$  Speaker:

88% at 400 mW 80% at 100 mW

80% at 100

- □ 3.8mA Quiescent Current
- $\square \quad 0.4 \mu A \text{ Shutdown Current}$
- □ Optimized PWM Output Stage Eliminates LC Output Filter
- □ Internally Generated 250-kHz Switching Frequency Eliminates Capacitor and Resistor
- □ Improved PSRR (-75 dB) and Wide Supply Voltage (2.5 V to 5.5 V) Eliminates Need for a Voltage Regulator
- □ Fully Differential Design Reduces RF Rectification and Eliminates Bypass Capacitor
- □ Improved CMRR Eliminates Two Input Coupling Capacitors
- □ MSOP8 and SOP8 package

## **General Description**

The BL6306 is a 2.6W high efficiency filter-free class-D audio power amplifier that requires only three external components.

Features like 88% efficiency, -75dB PSRR, and improved RF-rectification immunity make the BL6306 ideal for cellular handsets. In cellular handsets, the earpiece, speaker phone, and melody ringer can each be driven by the BL6306.

# **Applications**

- □ Mobile phone、PDA、MID
- □ MP3/4、PMP
- Portable electronic devices

## **Order Information**

Part Number	Package	Shipping
BL6306MM	MSOP8	3000 pcs / Tape & Reel
BL6306SO	SOP8	2500 pcs / Tape & Reel



**BL6306** 

# <u>Pin Diagrams</u>



# **<u>Pin Description</u>**

Pin #	Name	Description	
1	SDB	Shutdown terminal (low active)	
2	NC	C (No internal connection)	
3	IN+	Positive differential input	
4	IN-	Negative differential input	
5	VO+	Positive BTL output	
6	VDD	Power Supply	
7	PGND	Power Ground	
8	VO-	Negative BTL output	

# **Function Block Diagram**



**Notes:** Total Voltage Gain =  $Av1 \times Av2 = 2 \times \frac{150k}{R_1}$ 

### Figure 1. Function Block Diagram



# **Application Circuit**



Figure 2. BL6306 Application Schematic With Differential Input



Figure 3. BL6306 Application Schematic With Differential Input and Input Capacitors



Figure 4. BL6306 Application Schematic With Single-Ended Input



## **Absolute Maximum Ratings**

Supply Voltage	-0.3V to 6V
Input Voltage	-0.3V to VDD+0.3V
Storage Temperature	-65℃ to +150℃
Operating Temperature Rang	ge $-40^{\circ}$ C to $+85^{\circ}$ C

**NOTE:** <u>Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating</u> <u>Rating indicate conditions for which the device is functional, but do not guarantee specific performance limits.</u>

## **Electrical Characteristics**

The following specifications apply for the circuit shown in Figure 5.

 $T_A = 25$  °C, unless otherwise specified.

	Donomotor	Conditions		Unita		
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
I <sub>SD</sub>	Shutdown Current	V <sub>IN</sub> =0V, V <sub>SDB</sub> =0V, No Load		0.4	2	uA
		$V_{DD} = 2.5 V, V_{IN} = 0 V, No Load$		2.2	3.2	
$I_Q$	Quiescent Current	$V_{DD} = 3.6V, V_{IN} = 0V, No Load$		2.6		mA
		$V_{DD}$ = 5.5V, $V_{IN}$ = 0V, No Load		3.8	8	
	O to t Offici Values	$V_{IN} = 0V, A_V = 2V/V,$		2	25	mV
V OS	Output Offset Voltage	$V_{DD} = 2.5 V$ to 5.5 V		2		
PSRR	Power Supply Rejection Ratio	$V_{DD} = 2.5 V$ to 5.5 V		-75		dB
		$V_{DD} = 2.5 V$ to 5.5 V,				
CMRR	Common Mode Rejection Ratio	$V_{\rm IC} = V_{\rm DD}/2$ to 0.5V,		-68		dB
		$V_{\rm IC} = V_{\rm DD}/2$ to $V_{\rm DD}$ - 0.8V				
F <sub>SW</sub>	Modulation frequency	$V_{DD} = 2.5 V$ to 5.5 V	200	250	300	kHz
	x7.1.		270k	300k	330k	17/17
$A_{\rm V}$	voltage gain	$v_{DD} = 2.5 v$ to 5.5 v	R <sub>I</sub>	R <sub>I</sub>	R <sub>I</sub>	V/V
R <sub>SDB</sub>	Resistance from SDB to GND			300		kΩ
ZI	Input impedance		135	150	165	kΩ
T <sub>WU</sub>	Wake-up time from shutdown	$V_{DD} = 3.6V$		32		mS
		$V_{DD} = 2.5 V$		700		
r <sub>DS(on)</sub>	Drain-Source resistance (on-state)	$V_{DD} = 3.6V$		500		mΩ
		$V_{DD} = 5.5 V$		400		
V <sub>SDIH</sub>	Shutdown Voltage Input High		1.3			V
V <sub>SDIL</sub>	Shutdown Voltage Input Low				0.4	V



# **Operating Characteristics**

 $\Box$  V<sub>DD</sub> = 5V, R<sub>I</sub> = 150k $\Omega$ , T<sub>A</sub> = 25°C, unless otherwise specified.

Symbol	Parameter	Conditions	Spec			Unita
Symbol			Min.	Тур.	Max.	Units
	THD+N=10%, f=1KHz, $R_L = 4\Omega$		2.60			
	Output Power	THD+N=1%, f=1KHz, $R_L = 4\Omega$		2.10		W
P <sub>0</sub>		THD+N=10%, f=1KHz, $R_L = 8\Omega$		1.60		
	THD+N=1%, f=1KHz, $R_L = 8\Omega$		1.30			
THD+N	Total Harmonic			0.21		0/
	Distortion + Noise	$PO=1.0$ wrms, $I=1$ kHz, $K_L = 802$		0.21		%
SNR	Signal-to-Noise ratio	$V_{DD}=5V$ , Po=1.0Wrms, $R_L = 8\Omega$		91		dB

### $\Box$ V<sub>DD</sub> = 3.6V, R<sub>I</sub> = 150k $\Omega$ , T<sub>A</sub> = 25°C, unless otherwise specified.

Symbol Parameter Conditions		Conditions		Spec			Unita	
		•	Min.	Тур.	Max.	Units		
		THD+N=10%, f=1KHz, $R_L = 4$	Ω		1.35			
р	Output Douvor	THD+N=1%, f=1KHz, $R_L = 4\Omega$			1.08		** 7	
P <sub>0</sub>	Output Power	THD+N=10%, f=1KHz, $R_L = 8$	Ω		0.85		vv	
		THD+N=1%, f=1KHz, $R_L = 8\Omega$	2		0.69			
THD+N	Total Harmonic Distortion + Noise	Po=0.5Wrms, f=1kHz, $R_L = 8\Omega$	1		0.21		%	
K <sub>SVR</sub>	Supply ripple rejection ratio	$V_{DD}$ = 3.6V, input ac-grounded f=217Hz, V(Ripple)=200mV <sub>PP</sub>	with $C_I = 2uF$		-65		dB	
V	Output voltaga naiga	$V_{DD} = 3.6V$ , input ac-grounded	No weighting		100		υV	
v <sub>n</sub>	Output voltage noise	with $C_I = 2uF$ , f=20~20kHz	A weighting		75		u v <sub>RMS</sub>	
CMRR	Common Mode	V = 3.6V V = 1 V = 1217	V = 2 (V V = 1 V = 217 U		-70		dB	
CIVIKK	Rejection Ratio	$v_{\rm DD} = 5.0 v, v_{\rm IC} = 1 v_{\rm PP}, 1 = 21/1$	112		-70		uБ	

### $\Box$ V<sub>DD</sub> = 2.5V, R<sub>I</sub> = 150k $\Omega$ , T<sub>A</sub> = 25°C, unless otherwise specified.

Sympol	Parameter	Conditions	Spec			I.I
Symbol			Min.	Тур.	Max.	Units
		THD+N=10%, f=1KHz, $R_L = 4\Omega$		0.60		
P <sub>O</sub> Output Power	THD+N=1%, f=1KHz, $R_L = 4\Omega$		0.51		W	
	THD+N=10%, f=1KHz, $R_L = 8\Omega$		0.40			
		THD+N=1%, f=1KHz, $R_L = 8\Omega$		0.33		
THD+N To Di	Total Harmonic			0.21		0/
	Distortion + Noise	$PO=0.2$ wrms, $I=1$ kHz, $K_L = 8\Omega$		0.21		70



## **Test Circuit**



Figure 5. BL6306 test set up circuit





- Notes: 1>. C<sub>S</sub> should be placed as close as possible to VDD/GND pad of the device
  - 2>. Ci should be shorted for any Common-Mode input voltage measurement
  - 3>. A 33uH inductor should be used in series with  $R_L$  for efficiency measurement
  - 4>. The 30 kHz LPF (shown in figure 5) is required even if the analyzer has an internal LPF

## **Component Recommended**

Due to the weak noise immunity of the single-ended input application, the differential input application should be used whenever possible. The typical component values are listed in the table:

R <sub>I</sub>	CI	C <sub>S</sub>
150 k	3.3 nF	2 uF

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- (1)  $C_1$  should have a tolerance of  $\pm 10\%$  or better to reduce impedance mismatch.
- (2) Use 1% tolerance resistors or better to keep the performance optimized, and place the R<sub>I</sub> close to the device to limit noise injection on the high-impedance nodes.

### Input Resistors (R<sub>I</sub>) & Capacitors (C<sub>I</sub>)

The input resistors  $(R_I)$  set the total voltage gain of the amplifier according to Eq1

$$Gain = \frac{2 \times 150k\Omega}{R_I} \quad \left(\frac{V}{V}\right) \qquad Eq1$$

The input resistor matching directly affects the CMRR, PSRR, and the second harmonic distortion cancellation.

If a differential signal source is used, and the signal is biased from  $0.5V \sim V_{DD}$ -0.8V (shown in Figure2), the input capacitor (C<sub>1</sub>) is not required.

If the input signal is not biased within the recommended common-mode input range in differential input application (shown in Figure3), or in a single-ended input application (shown in Figure4), the input coupling capacitors are required.

If the input coupling capacitors are used, the  $R_1$  and  $C_1$  form a high-pass filter (HPF). The corner frequency ( $f_C$ ) of the HPF can be calculated by *Eq2* 

$$f_C = \frac{1}{2\pi \cdot R_I \cdot C_I} \quad (Hz) \qquad \qquad Eq2$$

#### **Decoupling Capacitor (Cs)**

A good low equivalent-series-resistance (ESR) ceramic capacitor ( $C_S$ ), used as power supply decoupling capacitor ( $C_S$ ), is required for high power supply rejection (PSRR), high efficiency and low total harmonic distortion (THD).  $C_S$  is 2µF, placed as close as possible to the device VDD pin.



## **Package Dimensions**

#### SOP8





**MSOP8** 

3.000±0.1

RO. 127



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